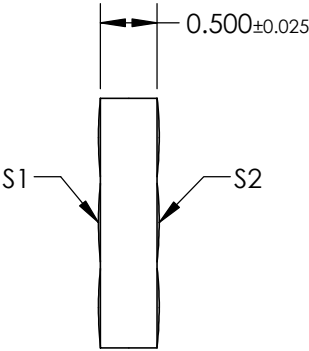
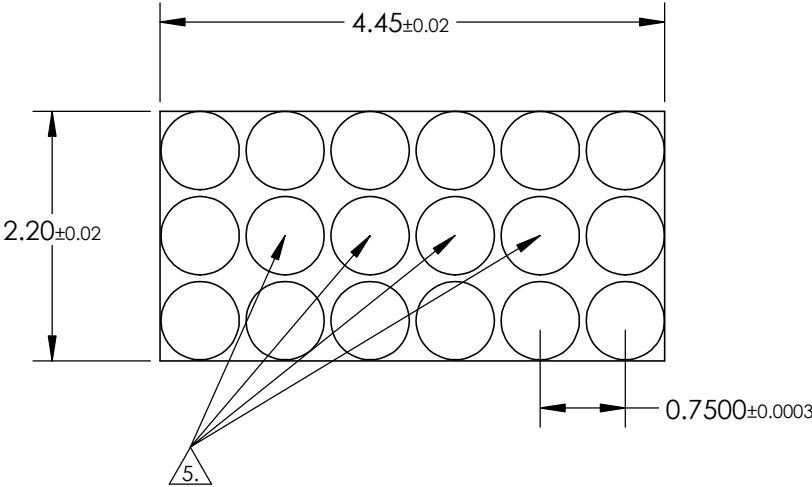
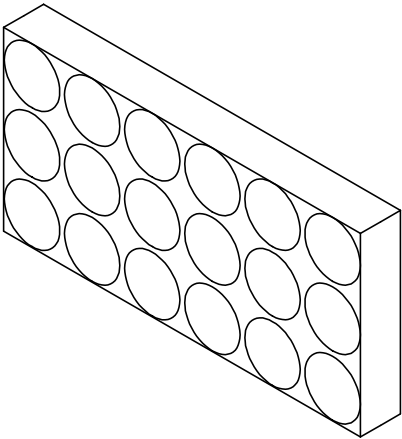


NOTES:

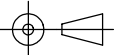
- 1. SUBSTRATE:  
Silicon
- 2. COATING (APPLY ACROSS COATING APERTURE):  
S1 & S2: R(AVG) ≤0.5% @ 1250 - 1620
- 3. WORKING DISTANCE (mm):  
1.202
- 4. MODE FIELD DIAMETER (mm):  
Source: 0.0092  
Target: 0.25
- 5. ACTIVE LENSES CENTERED ON SUBSTRATE
- 6. ROHS: COMPLIANT



SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICE  
DIMENSIONS ARE FOR REFERENCE ONLY

**FOR INFORMATION ONLY:  
DO NOT MANUFACTURE  
PARTS TO THIS DRAWING**

**EO<sup>®</sup> Edmund Optics<sup>®</sup>**

THIRD ANGLE PROJECTION 		TITLE	4.45 x 2.20mm, 3.378 ROC, 750µm Pitch, Silicon, 1 x 4 Linear Microlens Array	
ALL DIMS IN	mm	DWG NO	21180	SHEET 1 OF 1